

	<h2 style="color: red;">FDMS8660AS</h2>
	<p>Hersteller-Teilenummer: FDMS8660AS</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 30V 28A POWER56</p> <hr/> <p>Datenblätter:  FDMS8660AS.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 1346 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FDMS8660AS
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 28A POWER56
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	1346 pcs Stock
detaillierte Beschreibung	N-Channel 30V 28A (Ta), 49A (Tc) 2.5W (Ta), 104W
Serie	PowerTrench®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	8-PQFN (5x6)
Verlustleistung (max)	2.5W (Ta), 104W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	28A (Ta), 49A (Tc)
Rds On (Max) @ Id, Vgs	2.1 mOhm @ 28A, 10V
VGS (th) (Max) @ Id	3V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	83nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	5865pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FDMS8660ASTR


















































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Sie können auch interessiert sein:

 <p>FDMS8660S AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 25A POWER56</p>	 <p>FDMS86581-F085 AMI Semiconductor / ON Semiconductor MOSFET N-CHANNEL 60V 30A 8PQFN</p>	 <p>FDMS8660AS Fairchild/ON Semiconductor MOSFET N-CH 30V 28A POWER56</p>	 <p>FDMS86581_085 Fairchild/ON Semiconductor FDMS86581_085 FAIRCHILD</p>
 <p>FDMS8660S Fairchild/ON Semiconductor MOSFET N-CH 30V 25A POWER56</p>	 <p>FDMS8661AS FAIRCHILD FAIRCHILD PQOAM</p>	 <p>FDMS86569_F085 Fairchild/ON Semiconductor MOSFET N-CH 60V 65A POWER56</p>	 <p>FDMS86580-F085 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 50A POWER56</p>

heiße Teile

Mehr

 FDMS86200	 FDMS86201	 FDMS86201	 FDMS8622	 FDMS8622
 FDMS86250	 FDMS86250	 FDMS86257	 FDMS86300	 FDMS86300
 FDMS86320	 FDMS86320	 FDMS86322	 FDMS86322	 FDMS86500L
 FDMS86500L	 FDMS86520	 FDMS86520	 FDMS86520L	 FDMS86520L
 FDMS86540	 FDMS86540	 FDMS86550	 FDMS86550	 FDMS86581_085
 FDMS8660AS	 FDMS8660S	 FDMS8660S	 FDMS8670AS	 FDMS8670AS
 FDMS8670S	 FDMS8670S	 FDMS8672AS	 FDMS8672AS	 FDMS8672S
 FDMS8672S	 FDMS8674	 FDMS8674	 FDMS8680	 FDMS8680
 FDMS8690	 FDMS8690	 FDMS8692	 FDMS8692	 FDMS8692S
 FDMS8820	 FDMS8820	 FDMS8880	 FDMS8880	 FDMS8888

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